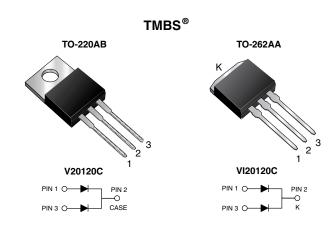
New Product



Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.54$ V at $I_F = 5$ A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V _{RRM}	120 V				
I _{FSM}	120 A				
V_F at $I_F = 10$ A	0.64 V				
T _J max.	150 °C				

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER		SYMBOL	V20120C	VI20120C	UNIT		
Maximum repetitive peak reverse voltage		V _{RRM}	120		V		
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	20 10		A		
	per diode						
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	120		А		
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs		
Operating junction and storage temperature range		T _J , T _{STG}	- 40 tc	9 + 150	°C		

RoHS COMPLIANT HALOGEN

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V20120C, VI20120C

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F (1)	0.62	-	V		
	I _F = 10 A			0.81	0.90			
	I _F = 5 A	- T _A = 125 °C		0.54	-			
	I _F = 10 A			0.64	0.72			
Reverse current per diode	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	8	-	μA		
		T _A = 125 °C		6	-	mA		
	V _B = 120 V	T _A = 25 °C		-	700	μΑ		
		T _A = 125 °C		14	45	mA		

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	V20120C	VI20120C	UNIT	
Typical thermal resistance per diode	R _{θJC}	2.8		°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V20120C-M3/4W	1.88	4W	50/tube	Tube		
TO-262AA	VI20120C-M3/4W	1.45	4W	50/tube	Tube		
TO-220AB	V20120CHM3/4W (1)	1.88	4W	50/tube	Tube		
TO-262AA	VI20120CHM3/4W ⁽¹⁾	1.45	4W	50/tube	Tube		

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

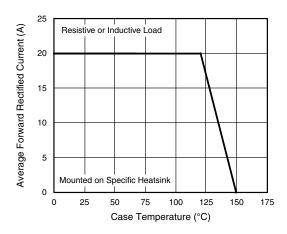


Fig. 1 - Maximum Forward Current Derating Curve

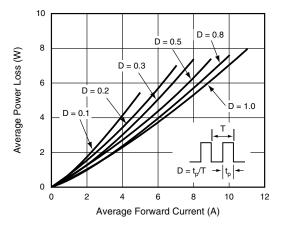


Fig. 2 - Forward Power Loss Characteristics Per Diode

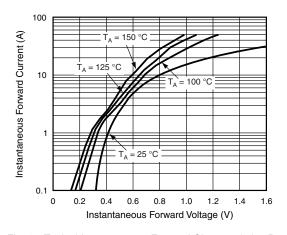


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

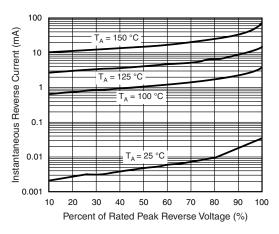


Fig. 4 - Typical Reverse Characteristics Per Diode

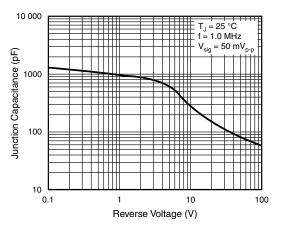


Fig. 5 - Typical Junction Capacitance Per Diode

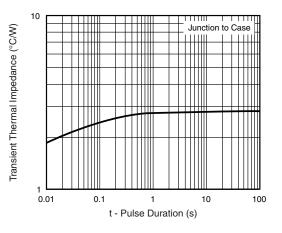


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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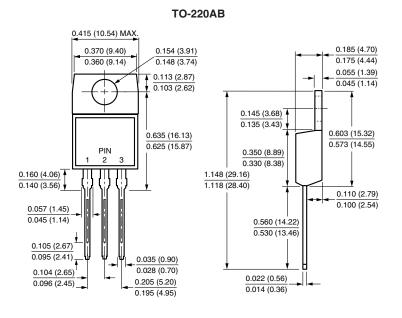
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V20120C, VI20120C

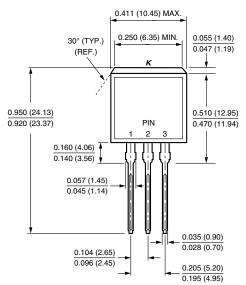
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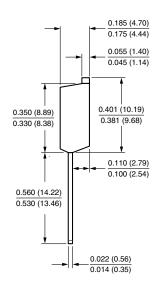
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA





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